Preliminary

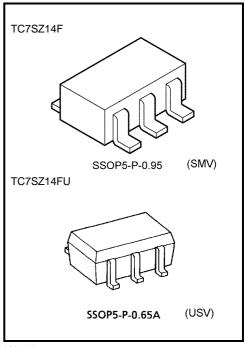
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZ14F,TC7SZ14FU

Schmitt Inverter

Features

- High output drive: ±24 mA (min) @VCC = 3 V
- High speed: $t_{pd} = 3.7 \text{ ns (typ.)} @V_{CC} = 5 \text{ V}, 50 \text{ pF}$
- Wide operating voltage range: $V_{CC (opr)} = 1.65 \text{ to } 5.5 \text{ V}$
- High latch-up immunity: Higher than or equal to ±500 mA
- High ESD : Higher than or equal to ± 200 V (JEITA) : Higher than or equal to ± 2000 V (MIL)
- Power-down protection is provided on all inputs and outputs.
- \bullet Matches the performance of TC74LCX Series when operated at 3.3~V



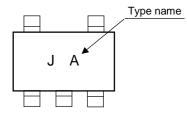
Weight:

SSOP5-P-0.95 : 0.016 g (typ.) SSOP5-P-0.65A : 0.006 g (typ.)

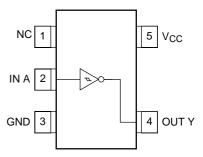
Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V _{CC}	-0.5 to 6	٧	
DC input voltage	V _{IN}	-0.5 to 6	V	
DC output voltage	V _{OUT}	-0.5 to 6	V	
Input diode current	I _{IK}	-20	mA	
Output diode current	I _{OK}	-20	mA	
DC output current	I _{OUT}	±50	mA	
DC V _{CC} /ground current	I _{CC}	±50	mA	
Power dissipation	P_{D}	200	mW	
Storage temperature	T _{stg}	-65 to 150	°C	
Lead temperature (10 s)	TL	260	°C	

Marking



Pin Assignment (top view)



Logic Diagram

Truth Table



А	Υ
L	Н
Н	L

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	Voc	1.65 to 5.5	V	
Supply voltage	Vcc	1.5 to 5.5 (Note 1)	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 2)	V	
Output voltage	VOU1	0 to V _{CC} (Note 3)	٧	
Operating temperature	T _{opr}	-40 to 85	°C	

Note 1: Date retention only

Note 2: $V_{CC} = 0 V$

Note 3: High or Low State

Electrical Characteristics

DC Electrical Characteristics

Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
Onaracionstics Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
Positive threshold voltage		_	1.65	0.6	1.0	1.4	0.65	1.4	
			1.8	0.7	1.1	1.5	0.7	1.5	
			2.3	1.0	1.4	1.8	1.0	1.8	
	V _P		3.0	1.3	1.75	2.2	1.3	2.2	
			4.5	1.9	2.45	3.1	1.9	3.1	
			5.5	2.2	2.9	3.6	2.2	3.6	V
	V _N	_	1.65	0.2	0.5	0.8	0.2	0.8	V
			1.8	0.25	0.55	0.9	0.25	0.9	
No sections the second state of			2.3	0.40	0.75	1.15	0.40	1.15	
Negative threshold voltage			3.0	0.6	1.0	1.5	0.6	1.5	
			4.5	1.0	1.43	2.0	1.0	2.0	
			5.5	1.2	1.70	2.4	1.2	2.4	
	V _H	_	1.65	0.1	0.48	0.9	0.1	1.0	
Hysteresis voltage			1.8	0.15	0.54	1.0	0.15	1.0	
			2.3	0.25	0.65	1.1	0.25	1.1	
			3.0	0.4	0.77	1.2	0.4	1.2	- V -
			4.5	0.6	1.01	1.5	0.6	1.5	
			5.5	0.7	1.18	1.7	0.7	1.7	



Characteristics	Cumbal	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
Characteristics	Symbol	rest	Test Condition \		Min	Тур.	Max	Min	Max	Offic
			I _{OH} = -100 μA	1.65	1.55	1.65		1.55		
				1.8	1.7	1.8		1.7		
				2.3	2.2	2.3	_	2.2		
				3.0	2.9	3.0	_	2.9	_	
High-level output voltage	V _{OH}	$V_{IN} = V_{IL}$		4.5	4.4	4.5	_	4.4		
riigii-ievei output voitage	VOH	VIN - VIL	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52		1.29		
			$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15		1.9		
			$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8		2.4		
			$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3		
			$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	_	3.8	_	V
		$V_{IN} = V_{IH}$	I _{OL} = 100 μA	1.65	_	0	0.1	_	0.1	- V
				1.8	_	0	0.1	_	0.1	
				2.3	_	0	0.1	_	0.1	
				3.0	_	0	0.1	_	0.1	
I am land antent make as				4.5	_	0	0.1	_	0.1	
Low-level output voltage	V _{OL}		I _{OL} = 4 mA	1.65	_	0.08	0.24	_	0.24	
			I _{OL} = 8 mA	2.3	_	0.1	0.3	_	0.3	
			I _{OL} = 16 mA	3.0	_	0.15	0.4	_	0.4	
			I _{OL} = 24 mA	3.0	_	0.22	0.55	_	0.55	
			I _{OL} = 32 mA	4.5	_	0.22	0.55	_	0.55	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND 0~		0~5.5	_	_	±1	_	±10	μА
Power OFF leakage current	l _{OFF}	V _{IN} or V _{OUT} = 5.5 V		0.0	_	_	1	_	10	μА
Quiescent supply current	Icc	V _{IN} = 5.5 V or GND 1		1.65~5.5	_	_	1	_	10	μΑ

AC Electrical Characteristics (Unless otherwise specified Input: $t_r = t_f = 3$ ns)

Chanastanistica	Courselle ed	Took Condition		Ta = 25°C			Ta = -4	Unit	
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offit
Propagation delay time	^t pLH ^t pHL	KL = 1 IVIS2	1.65	2.0	9.1	15.0	2.0	15.6	ns
			1.8	2.0	7.6	12.5	2.0	13	
			2.5 ± 0.2	1.0	5.0	9.0	1.0	9.5	
			3.3 ± 0.3	1.0	3.7	6.3	1.0	6.5	
			5.0 ± 0.5	0.5	3.1	5.2	0.5	5.5	
		$C_L = 50 \text{ pF},$ $R_L = 500 \Omega$	3.3 ± 0.3	1.5	4.4	7.2	1.5	7.5	
			5.0 ± 0.5	0.5	3.7	5.9	0.8	6.2	
Input capacitance	C _{IN}	_		_	_	_	_	_	pF
Power dissipation capacitance	C _{PD}		(Note 4)	_	_	_	_	_	pF

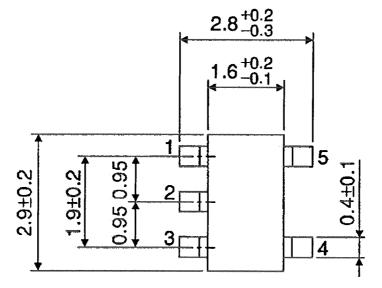
Note 4: CPD is defined as the value of the internal equivalent capacitance which is Calculated from the operating current consumption without load.

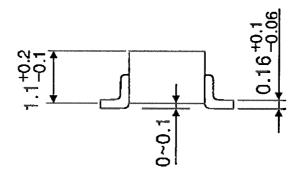
Average operating current can be obtained by the equation.

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Package Dimensions

SSOP5-P-0.95 Unit: mm



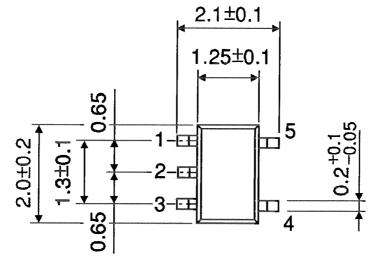


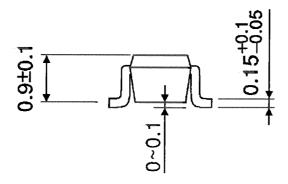
Weight: 0.016 g (typ.)

4

Package Dimensions

SSOP5-P-0.65A Unit: mm





5

Weight: 0.006 g (typ.)

2002-04-01

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000707EBA

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